

深圳市晶泰源电子有限公司

BC817-16 BC817-25

BC817-40 TRANSISTOR (NPN)

FEATURES

- For general AF applications
- High collector current
- High current gain
- Low collector-emitter saturation voltage
- Complementary types: BC807 (PNP)

SOT-23



1. BASE
2. EMITTER
3. COLLECTOR

MAXIMUM RATINGS ($T_A=25^{\circ}\text{C}$ unless otherwise noted)

| Symbol | Parameter | Value | Units |
|-----------|-------------------------------|---------|--------------------|
| V_{CBO} | Collector-Base Voltage | 50 | V |
| V_{CEO} | Collector-Emitter Voltage | 45 | V |
| V_{EBO} | Emitter-Base Voltage | 5 | V |
| I_C | Collector Current -Continuous | 0.5 | A |
| P_C | Collector Power Dissipation | 0.2 | W |
| T_j | Junction Temperature | 150 | $^{\circ}\text{C}$ |
| T_{stg} | Storage Temperature | -55-150 | $^{\circ}\text{C}$ |

ELECTRICAL CHARACTERISTICS ($T_{amb}=25^{\circ}\text{C}$ unless otherwise specified)

| Parameter | Symbol | Test conditions | MIN | MAX | UNIT |
|--------------------------------------|---------------|----------------------------------------------------------|-----|-----|---------------|
| Collector-base breakdown voltage | V_{CBO} | $I_C=10\mu\text{A}, I_E=0$ | 50 | | V |
| Collector-emitter breakdown voltage | V_{CEO} | $I_C=10\text{mA}, I_B=0$ | 45 | | V |
| Emitter-base breakdown voltage | V_{EBO} | $I_E=1\mu\text{A}, I_C=0$ | 5 | | V |
| Collector cut-off current | I_{CBO} | $V_{CB}=45\text{V}, I_E=0$ | | 0.1 | μA |
| Emitter cut-off current | I_{EBO} | $V_{EB}=4\text{V}, I_C=0$ | | 0.1 | μA |
| DC current gain | $h_{FE(1)}$ | $V_{CE}=1\text{V}, I_C=100\text{mA}$ | 100 | 600 | |
| | $h_{FE(2)}$ | $V_{CE}=1\text{V}, I_C=500\text{mA}$ | 40 | | |
| Collector-emitter saturation voltage | $V_{CE(sat)}$ | $I_C=500\text{mA}, I_B=50\text{mA}$ | | 0.7 | V |
| Base-emitter saturation voltage | $V_{BE(sat)}$ | $I_C=500\text{mA}, I_B=50\text{mA}$ | | 1.2 | V |
| Base-emitter voltage | V_{BE} | $V_{CE}=1\text{V}, I_C=500\text{mA}$ | | 1.2 | V |
| Collector capacitance | C_{ob} | $V_{CB}=10\text{V}, f=1\text{MHz}$ | | 10 | pF |
| Transition frequency | f_T | $V_{CE}=5\text{V}, I_C=10\text{mA}$ $f=100\text{MHz}$ | 100 | | MHz |

CLASSIFICATION OF $h_{FE(1)}$

| Rank | BC817-16 | BC817-25 | BC817-40 |
|---------|----------|----------|----------|
| Range | 100-250 | 160-400 | 250-600 |
| Marking | 6A | 6B | 6C |